



COMBINED DECLARATION AND POWER OF ATTORNEY

This declaration is of th	e following type:			
	design supplemental age of PCT continuation continuation	n-in-part		
As a below named inve	ntor, I hereby declare that			
My residence, post offic	ce address, and citizenship are as sta	ted below next to my nam	ie.	
inventor (if plural name	mal, first, and sole inventor (if only es are listed below) of the subject made: Semiconductor Device a	natter which is claimed ar	nd for which a patent is sou	ight
the specification of whi	ch:			
X is atta	ached hereto. filed on <i>(if app</i>	as Serial No.	and was amen	ded
☐ was	described and claimed in PCT Into on(if any).	ernational Application N	o. PCT/ uant to PCT Article 19	
	ved and understand the contents of the content	he specification identified	l above, including the claim	(s),
I acknowledge the dut above in accordance wi	y to disclose information that is m th 37 CFR §1.56.	aterial to the examination	n of the application identif	fied
certificate or of any PC States of America listed design registration, or i country other than the V	benefits pursuant to 35 USC §119(T international patent application(s) I below and have also identified be nventor's certificate or any PCT int Jnited States of America filed by m) from which the benefit of priority in	designating at least one low any foreign applicati ernational patent applicat e for the same invention	country other than the Uni on(s) for patent, utility mod tion(s) designating at least of	ited del, one
PRIOR	FOREIGN PATENTS UTILITY MC APPLICATIONS BENEFIT CLA			
COUNTRY	PRIOR FOREIGN APPLICATION	DATE OF FILING (day,month, year)	PRIORITY CLAIMED UNDER 35 USC § 119(a	語
Japan	P 11-201609	15/07/1999	X YES NO	'n
			YES	
			YES	27.1

I claim the benefit pursuant to 3	C §119(e) of	the following United	States province al	patent application(s)

PRIOR U.S. PROVI BENEFIT CLA		NT APPLICATIONS, 35 USC §119(e)
APPLICATION NO.	7	DATE OF FILING (day,month,year)

I claim the benefit pursuant to 35 USC §120 of any United States patent application(s) or PCT international patent application(s) designating the United States of America listed below and, insofar as the subject matter of each of the claims of this patent application is not disclosed in the prior patent application(s) in the manner provided by the first paragraph of 35 USC §112, I acknowledge the duty to disclose material information as defined in 37 CFR §1.56 effective between the filing date of the prior patent application(s) and the national or PCT international filing date of this patent application.

PRIOR U.S. PATENT APPLICATIONS OR PCT I APPLICATIONS DESIGNATING THE U.S., BENEFIT	
U.S. PATENT APPLICATIONS	Status (check one)
SERIAL NUMBER U.S. FILING DATE	PATENTED PENDING ABANDONED
1.	
2.	
3.	
PCT APPLICATIONS DESIGNATING THE U.S.	Status (check one)
PCT APPLICATION NO. PCT FILING U.S. SERIAL NOS. DATE ASSIGNED (if any)	PATENTED PENDING ABANDONED
4.	
5.	
6.	

As a named inventor, I appoint the following attorneys to prosecute this application and transact all business in the Patent and Trademark Office connected with this patent application.

John M. Belz, Reg. 30,359 Jeffrey A. Wyand, Reg. 29,458 Jeremy M. Jay, Reg. 33,587 Michael H. Tobias, Reg. 32,948 Gregory A. Hunt, Reg. 41,085

Patrick R. Jewik, Reg. 40,456 Joseph S. Ostroff, Reg. 39,321

I further direct that correspondence concerning this application be sent to:

LEYDIG, VOIT & MAYER, LTD.
700 Thirteenth Street, N.W., Suite 300
Washington, D.C. 20005
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Post Office Address:

I authorize my attorneys to account and follow instructions from AOYAMA ARTNERS regarding any matter related to the preparation, examination, grant, and maintenance of the patent application identified above, any continuation, continuation-in-part, or divisional patent application based on the patent application identified above, and any patent issuing from that patent application, until I or my assigns withdraw this authorization in writing.

I declare that all statements made herein of my own knowledge are true, that all statements made on information and belief are believed to be true, that these statements were made with the knowledge that willful false statements and the like so made are punishable by fine or imprisonment, or both, under Section 1001 of Title 18 of the United States Code, and that such willful false statements may jeopardize the validity of the application or any patent issued thereon.

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Full name of third joint inventor, if any:
Inventor's signature
Date Country of Citizenship:
Residence:

PATENT

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

#5 Associate
Pla
b.27-00
R. Notes

In re application of:

SUZUKI et al.

Serial No:

None assigned

Filed:

July 11, 2000

For:

Semiconductor Device And Process

For Manufacturing The Same

ASSOCIATE POWER OF ATTORNEY

Assistant Commissioner for Patents Washington, D.C. 20231

Dear Sir:

I, Jeffrey A. Wyand, attorney of record in the referenced patent application, grant an

Associate Power of Attorney to XAVIER PILLAI, Registration Number 39,799.

Respectfully submitted,

LEYDIG, VOIT & MAYER

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